

SANYO Semiconductors DATA SHEET

SBT250-06JS — Schottky Barrier Diode (Twin Type · Cathode Common)

60V, 25A Rectifier

Applications

· High frequency rectification (switching regulators, converters, choppers).

Features

- Tj=150°C.
- Low forward voltage (VF max=0.60V).
- · Short reverse recovery time.
- · Low switching noise.
- · High reliability due to highly reliable planar structure.
- · Attachment workability is good by Mica-less package.

Specifications

Absolute Maximum Ratings at Ta=25°C

Parameter	Symbol	Conditions	Ratings	Unit
Repetitive Peak Reverse Voltage	VRRM		60	V
Nonrepetitive Peak Reverse Surge Voltage	VRSM		66	V
Average Output Current	IO	50Hz resistive load, Sine wave Tc=73°C	25	Α
Surge Forward Current	IFSM	50Hz sine wave, 1 cycle	120	А
Junction Temperature	Tj		-55 to +150	°C
Storage Temperature	Tstg		-55 to +150	°C

Electrical Characteristics at Ta=25°C

Parameter	Symbol	Conditions	Ratings			Unit
			min	typ	max	Offic
Reverse Voltage	٧R	I _R =3mA, Tj=25°C*	60			V
Forward Voltage	٧F	I _F =10A, Tj=25°C*			0.60	V
Reverse Current	IR	V _R =30V, Tj=25°C*			0.3	mA

Note) * : Value per element

Continued on next page.

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SBT250-06JS

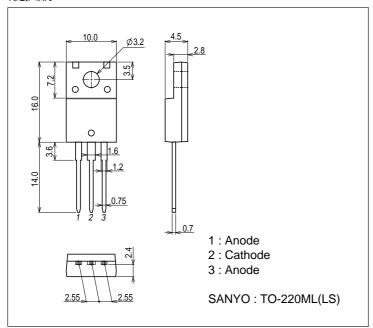
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Parameter	Symbol	Conditions	Ratings			Unit
			min	typ	max	Offic
Interterminal Capacitance	С	V _R =10V, Tj=25°C*		430		pF
Thermal Resistance	Rth(j-c)	Junction-Case : Smoothed DC			3.5	°C/W

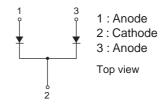
Note) * : Value per element

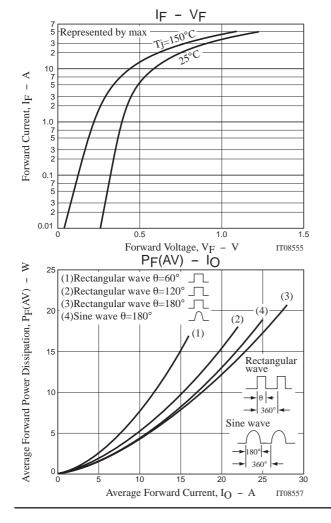
Package Dimensions

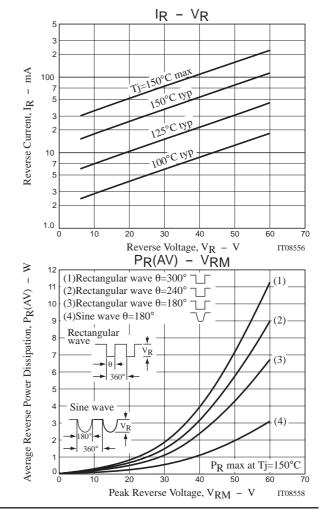
unit : mm (typ) 7525-001



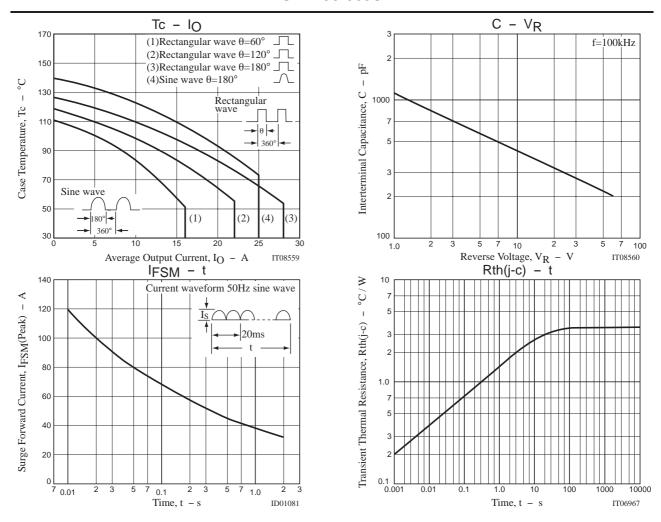
Electrical Connection







SBT250-06JS



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